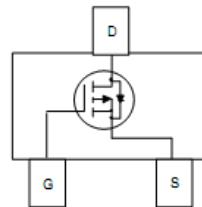
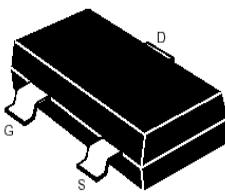


SOT-23**Features**

- Advanced trench process technology
- High Density Cell Design For Ultra Low On-Resistance

MAXIMUM RANTINGS

Characteristic	Symbol	Max	Unit
Drain-Source Voltage	BV_{DSS}	-30	V
Gate- Source Voltage	V_{GS}	± 20	V
Drain Current (continuous)	I_D	-4.1	A
Drain Current (pulsed)	I_{DM}	-16	A
Total Device Dissipation $T_A=25^\circ C$	P_D	1400	mW
Junction	T_J	150	$^\circ C$
Storage Temperature	T_{stg}	-55 to +150	$^\circ C$

Electrical Characteristics

Characteristic	Symbol	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage ($I_D = -250\mu A, V_{GS}=0V$)	BV_{DSS}	-30	—	—	V
Gate Threshold Voltage ($I_D = -250\mu A, V_{GS}=V_{DS}$)	$V_{GS(th)}$	-1	—	-2.5	V
Diode Forward Voltage Drop ($I_S = -1 A, V_{GS}=0V$)	V_{SD}	—	—	-1	V
Zero Gate Voltage Drain Current ($V_{GS}=0V, V_{DS} = -24V$) ($V_{GS}=0V, V_{DS} = -24V, T_A=25^\circ C$)	I_{DSS}	—	—	-1 -5	μA
Gate Body Leakage ($V_{GS}=\pm 20V, V_{DS}=0V$)	I_{GSS}	—	—	± 100	nA
Static Drain-Source On-State Resistance ($I_D = -4.1A, V_{GS} = -10V$)	$R_{DS(ON)}$	—	55	65	$m\Omega$
Static Drain-Source On-State Resistance ($I_D = -2A, V_{GS} = -4.5V$)	$R_{DS(ON)}$	—	75	95	$m\Omega$
Input Capacitance ($V_{GS}=0V, V_{DS} = -15V, f=1MHz$)	C_{iss}	—	260	—	pF
Output Capacitance ($V_{GS}=0V, V_{DS} = -15V, f=1MHz$)	C_{oss}	—	37	—	pF
Turn-ON Time ($V_{DS} = -15V, I_D = -10 A, R_{GEN}=6\Omega$)	$t_{(on)}$	—	6	—	ns
Turn-OFF Time ($V_{DS} = -15V, I_D = -10 A, R_{GEN}=6\Omega$)	$t_{(off)}$	—	20	—	ns

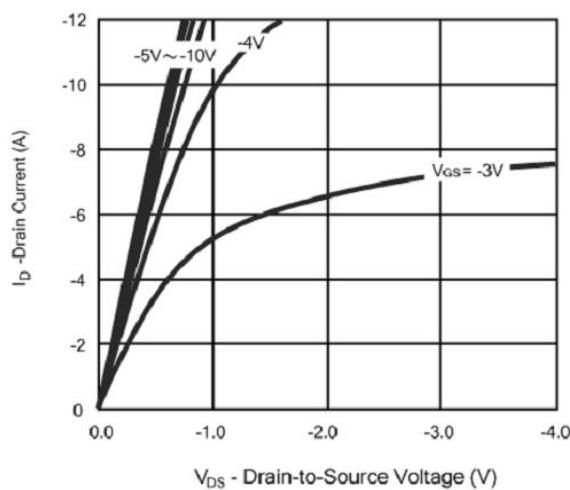


Figure 1: Output Characteristics

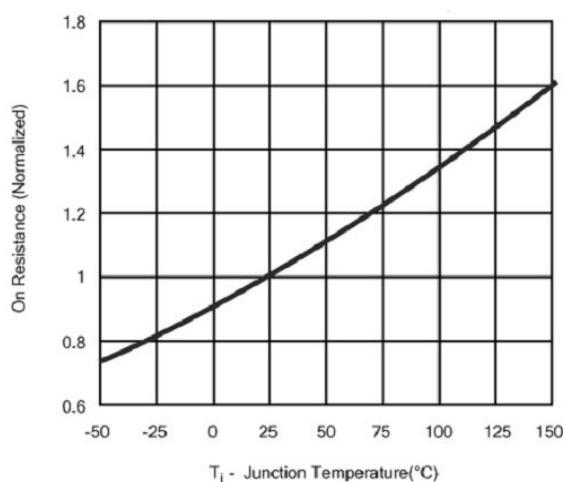


Figure 2: On-Resistance vs. Junction Temperature

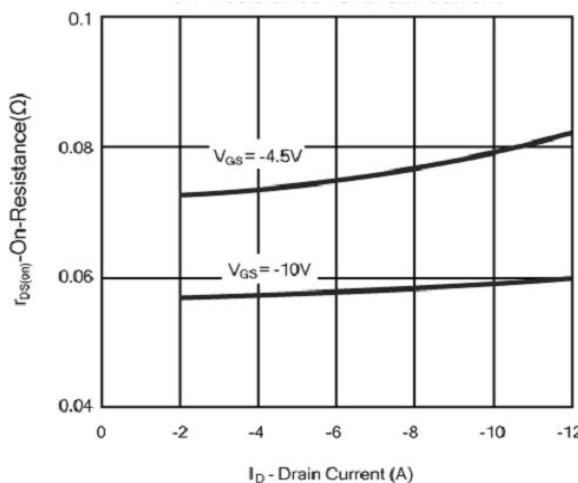


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

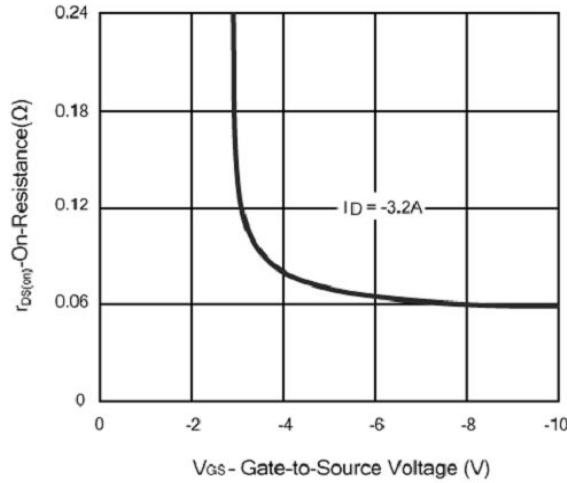


Figure 4: On-Resistance vs. Gate-Source Voltage

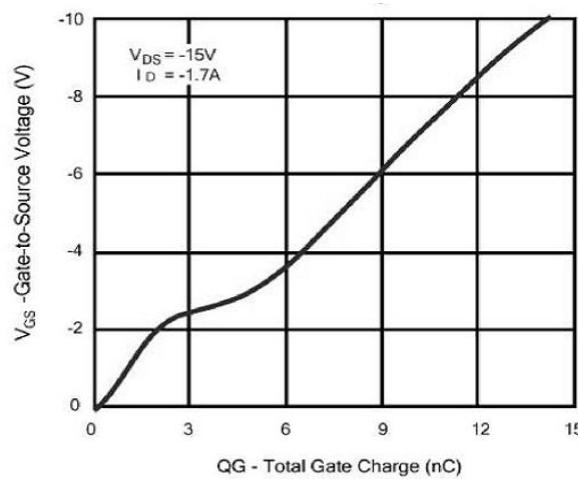


Figure 5: Gate-Charge Characteristics

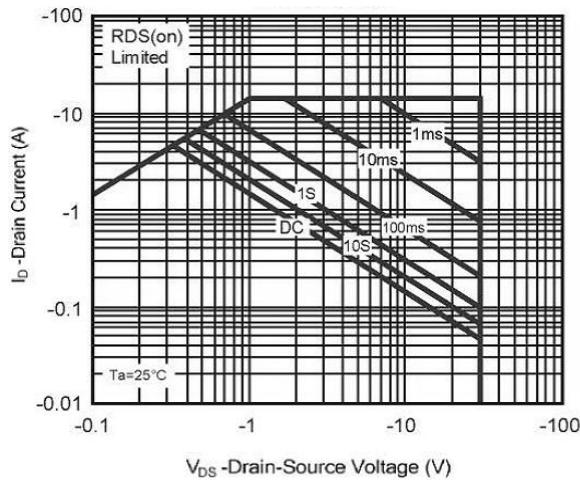
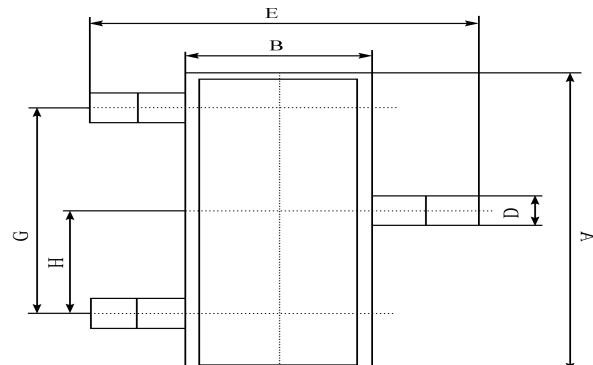


Figure 6: Safe Operating Area

**SOT-23 PACKAGE OUTLINE** Plastic surface mounted package

SOT-23	
A	2.90 ± 0.10
B	1.30 ± 0.10
C	1.00 ± 0.10
D	0.40 ± 0.10
E	2.40 ± 0.20
G	1.90 ± 0.10
H	0.95 ± 0.05
J	0.13 ± 0.05
K	$0.00-0.10$
M	≥ 0.2
N	0.60 ± 0.10
P	$7 \pm 2^\circ$

(UNIT): mm

